Modified Ring Power Divider Using Stepped-Impedance Resonator

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Abstract— In this paper, the design of a modified ring power divider dedicated for wideband communication or measurement systems is presented. The proposed power divider is built by using a conventional ring power divider and an additional Stepped-Impedance Resonator (SIR). The even-odd mode analysis is used to derive the design equations. In order to observe the bandwidth improvement, a comparative study between the designed device and the previously reported ring power divider is conducted. The electromagnetic (EM) simulated results show that the proposed divider has a fractional bandwidth of 90.2 % at the center frequency of 3.17 GHz. The measurement results of the fabricated prototype demonstrate high performance over the considered operational bandwidth from 1.7 GHz to 4.64 GHz with a return loss lower than -10 dB while maintaining a good insertion loss and a good isolation between the output ports. The maximum amplitude imbalance is better than 0.21 dB and the phase imbalance is better than 2.5 degrees between the output signals. The simulation and measurement results are in good agreement over the whole band of interest.

Index Terms— Microstrip, Ring Power divider, Stepped-impedance resonator (SIR); Wideband.

I. INTRODUCTION

Power dividers are extremely useful microwave components whose principal function is to equally split the incident signal between the two outputs while maintaining good isolation between them. They are used in different applications including measurement systems as well as antenna distribution circuits, communication and radar systems. Many efforts have been recently made to design wideband power dividers by opportunely modifying the classical Wilkinson structure [1].

The most usual way to make this device wideband is by adding two or more sections to the conventional structure [2]-[4] or by adding open-circuited stubs [5]-[6]. However, these structures add more circuit area to the conventional design. Other works, reported in the literature, propose broadband Wilkinson power dividers such as in [7] where double-sided parallel-strip line technique using similar structure at both the top and bottom layers with three isolation resistors at both layers is proposed. In [8], the proposed power divider using microstrip-to-slotline coupled structure and a top and bottom layers shows good performance over a 68.6 % bandwidth from 2.3 to 4.7 GHz. Another

broadband power divider achieving good in-band responses across a 62 % fractional bandwidth was proposed in [9] by arranging two open-circuited stubs and three coupled-line sections around the ring resonator. However, these power dividers require complex design configuration due to the use of different layers or coupled-line sections which makes the fabrication process more complicated.

Recently, a compact ring power divider has been proposed in [10]. It introduces a circular layout with the addition of two half-wave transmission lines to connect the 100 Ω isolation resistor, converting the layout in a ring circuit of 1.5 λ_g length. The corresponding electric lengths θ_1 and θ_2 are $\pi/2$ and π , respectively, and the normalized ring characteristic impedance z_{01} (which is equal to z_{02}) is found to be $\sqrt{2}$ [10]. The circuit has been rebuilt to operate at the center frequency of 3.12 GHz as shown in Fig. 1.

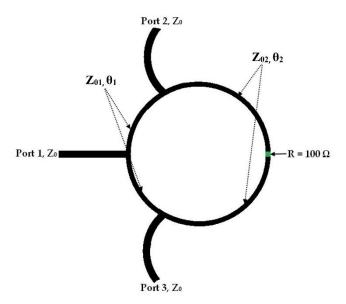


Fig. 1. Layout of the ring power divider proposed in [10].

This circuit is offering very good performance over a wide bandwidth compared to the traditional Wilkinson power divider. In addition, this design had shown more stability and larger bandwidth than previous implementations among valid solutions. Furthermore, this circuit has a size reduction of around 20 % compared to classical Wilkinson power divider and improved performances in terms of RF input/output matching and isolation between the output RF ports [11].

In this work, a modified ring power divider operating in the frequency band from 1.7 GHz to 4.64 GHz is introduced and it consists of the same circular structure as in [10] with the addition of a stepped-impedance resonator (SIR) to the old structure. The circuit in Fig. 2 represents the layout of the proposed ring power divider. For this structure, the simulation results show that the fractional bandwidth has a significant increase of 27.2 % compared to the old structure as it will be seen in section II and this without affecting the circuit size since the added element is inside the ring structure.

ISSN 2179-1074

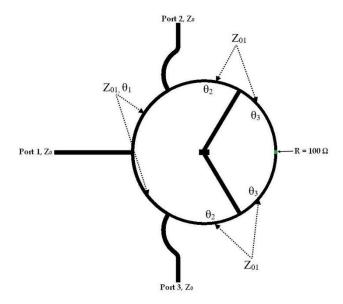


Fig. 2. Layout of the proposed ring power divider.

II. DESIGN AND SIMULATIONS

The circuit diagram of the proposed wideband ring power divider is shown in Fig. 3. It consists of six transmission lines of characteristic impedances (Z₀₁, Z₀₂, and Z₀₃), a Stepped-Impedance Resonator (SIR), and an isolation resistor R=100 Ω .

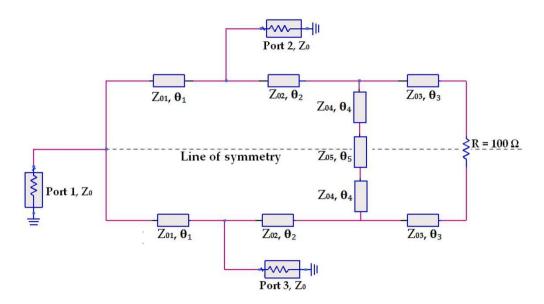


Fig. 3. Proposed structure of the modified ring power divider.

Microstrip resonators have been widely used in the design of microwave filters with wide stopband characteristics [12]-[14]. In addition, Stepped-impedance resonators (SIRs) have been found advantageous in the design of microstrip bandpass filters with good stopband performance [15]-[17]. A typical SIR is used to modify the structure of the ring power divider and is built by joining three microstrip-line sections of different characteristic impedances Z₀₄ and Z₀₅ as shown in Fig. 4. The microstrip line at the center has a characteristic impedance of Z_{05} with an electrical length of θ_5 whereas the identical lines at the two sides both have a characteristic impedance of Z₀₄ with an Brazilian Microwave and Optoelectronics Society-SBMO received 23 June 2019; for review 27 June 2019; accepted 18 Nov 2019

electrical length of θ_4 .

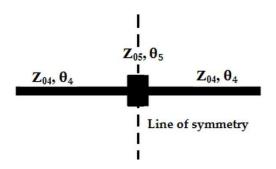


Fig. 4. Stepped impedance resonator (SIR) used structure.

As described in [16], the conditions for determining the resonance frequencies of a typical stepped impedance resonator (SIR) are given as:

$$K = \tan(\theta_5 / 2). \tan \theta_4 \qquad \text{(for odd mode)} \tag{1}$$

$$K \tan(\theta_5/2) = -\tan \theta_4$$
 (for even mode) (2)

Where $K = Z_{04} / Z_{05}$ is the impedance ratio of the SIR.

Let's define the stepped percentage α of the SIR as $\alpha = 2\theta_4/\theta_t$ where $\theta_t = (2\theta_4 + \theta_5)$ is the total length of the SIR. Then, equations (1) and (2) can be expressed as:

$$K.\cot\left(\frac{\alpha.\theta_t}{2}\right) = \tan\left(\frac{(1-\alpha).\theta_t}{2}\right)$$
 (for odd mode) (3)

$$K.\cot\left(\frac{\alpha.\theta_t}{2}\right) = -\cot\left(\frac{(1-\alpha).\theta_t}{2}\right)$$
 (for even mode) (4)

Fig. 5 shows the resonant electric length of the first spurious response mode with different impedance ratios K=1,1.5,2,3 as a parameter. By properly choosing different combinations of α and K values, the first two resonant modes can be combined together to create a wide passband [16].

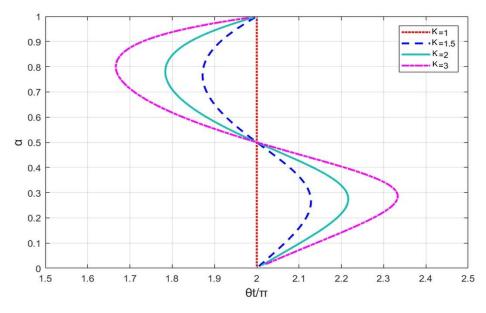


Fig. 5. Resonant electric length θ_t versus stepped percentage α with different impedance ratios K.

The structure of the proposed ring power divider is symmetric; thus, we can apply the even-odd mode analysis [18] in order to analyze the divider parameters. In this study, the known parameters as defined in the previous analysis [10] are the normalized characteristic impedances $z_{01} = z_{02} = z_{03} = z_{04} = \sqrt{2}$; and $\theta_1 = \pi/2$ and $(\theta_2 + \theta_3) = \pi$. The following analysis is performed in order to find the main characteristics of the added element to the old ring structure.

A. Even -mode analysis

In the even mode, ports 2 and 3 are excited by signals of the same magnitude and phase, which introduces a virtual open-circuit along the line of symmetry. By introducing the same voltages at the plane of symmetry there is no current flow through the line of symmetry and the presence of open circuits allows for eliminating the resistance R in the equivalent circuit as shown in Fig. 6. The calculation of the input impedance for the even-mode Z_{ine} viewed from port 2 corresponds to the equivalent impedances Z_{eq1e} and Z_{eq2e} connected in parallel.

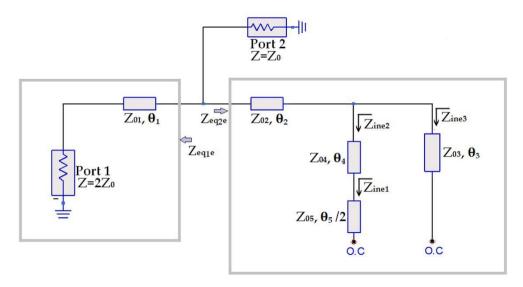


Fig. 6. Equivalent circuit of the proposed ring divider for odd-mode.

From the transmission line theory, we can easily calculate Z_{eq_1e} as the input impedance of a quarter-wave transmission line terminated by $2Z_0$:

$$Z_{eqle} = \frac{Z_{01}^{2}}{2Z_{0}} = \frac{2Z_{0}^{2}}{2Z_{0}} = Z_{0}$$
 (5)

Referring to Fig. 6, the input impedances Z_{ine1} and Z_{ine2} can be expressed as follows

$$Z_{ine1} = -j Z_{05} cot \left(\frac{\theta_5}{2}\right) \tag{6}$$

$$Z_{ine2} = \frac{Z_{04} \left(Z_{ine1} + j Z_{04} \tan \theta_4 \right)}{\left(Z_{04} + j Z_{ine1} \tan \theta_4 \right)}$$
 (7)

$$Z_{ine2} = \frac{-j Z_{04} \left(Z_{05} \cot \left(\theta_5 / 2 \right) - Z_{04} \tan \theta_4 \right)}{Z_{04} + Z_{05} \cot \left(\theta_5 / 2 \right) \tan \theta_4}$$
(8)

In a similar way, the admittance Y_{ine3} can be expressed as the input admittance of an open-circuited transmission line.

$$Y_{ine3} = \frac{1}{Z_{ine3}} = j Y_{03} tan \theta_3$$
 (9)

Let Z_X be the parallel combination of these impedances Z_{ine2} and Z_{ine3} , then the equivalent admittance Y_X can be written as:

$$Y_{X} = Y_{ine3} + Y_{ine2} = j \left[Y_{03} tan \theta_{3} + Y_{04} \frac{\left(Z_{04} + Z_{05} \cot \left(\theta_{5} / 2 \right) tan \theta_{4} \right)}{\left(Z_{05} \cot \left(\theta_{5} / 2 \right) - Z_{04} tan \theta_{4} \right)} \right]$$
(10)

The equivalent impedance Z_{eq2e} can be expressed as the input impedance of a transmission line terminated by Z_X :

$$Z_{eq2e} = \frac{Z_{02} \left(Z_X + j Z_{02} \tan \theta_2 \right)}{\left(Z_{02} + j Z_X \tan \theta_2 \right)}$$
(11)

Since the output is matched, the input admittance for the even-mode Y_{ine} viewed from port 2 should be equal to $Y_0=1/Z_0$:

$$Y_{ine} = \frac{1}{Z_{eale}} + \frac{1}{Z_{ea2e}} = \frac{1}{Z_0}$$
 (12)

By replacing Z_{eq1e} and Z_{eq2e} in (12) with their values in (5) and (11), this will result in

$$\frac{\left(Z_{02} + jZ_{x} tan \theta_{2}\right)}{Z_{02}\left(Z_{x} + jZ_{02} tan \theta_{2}\right)} = 0$$
(13)

This yields to

$$Y_{\rm v} = -iY_{\rm o2} \tan\theta_2 \tag{14}$$

Comparing (10) and (14), and since $Y_{03} = Y_{02}$; we have

$$Y_{03}\left(\tan\theta_{3} + \tan\theta_{2}\right) + Y_{04}\frac{\left(Z_{04} + Z_{05}\cot\left(\theta_{5}/2\right)\tan\theta_{4}\right)}{\left(Z_{05}\cot\left(\theta_{5}/2\right) - Z_{04}\tan\theta_{4}\right)} = 0$$
(15)

By using the trigonometric identity

$$(\tan \theta_3 + \tan \theta_2) = (\tan (\theta_3 + \theta_2))[1 - \tan \theta_3 \tan \theta_2]$$
 (16)

Then, since $(\theta_3 + \theta_2) = \pi$, we can simplify (15) to

$$Z_{04} + Z_{05} \cot(\theta_5/2) \tan \theta_4 = 0 \tag{17}$$

Which is the second resonance condition given by (2) for the even-mode resonance of a typical stepped-impedance resonator [16].

B. Odd -mode analysis

In the odd mode, ports 2 and 3 are excited by signals of the same amplitude but of opposite phases. The introduction of equal and contrary voltages implies a diverging current that can be represented by short circuits at the plane of symmetry which has the effect of introducing a virtual ground along the line of symmetry as shown in Fig. 7. In this analysis, we can choose $\theta_2 = \theta_3 = \pi/2$ in order to have a symmetric design which will reduce the computational complexity. The calculation of the input impedance Z_{ino} viewed from port 2 is simplified and corresponds to Z_{eq1} and Z_{eq2} connected in parallel.

From the transmission line theory, we can easily calculate Z_{eq1} as the input impedance of a short-circuited line.

$$Z_{eq1} = jZ_{01}tan\theta_1 \tag{18}$$

Referring to Fig. 7, the characteristic impedances Z_{ino1} and Z_{ino2} can be expressed as

$$Z_{ino1} = j Z_{05} tan(\theta_5/2) \tag{19}$$

$$Z_{ino2} = Z_{04} \frac{\left(Z_{ino1} + jZ_{04} \tan \theta_4\right)}{\left(Z_{04} + jZ_{ino1} \tan \theta_4\right)}$$
(20)

$$Z_{ino2} = \frac{j Z_{04} \left(Z_{05} tan \left(\theta_5 / 2 \right) + Z_{04} tan \theta_4 \right)}{\left(Z_{04} - Z_{05} tan \left(\theta_5 / 2 \right) tan \theta_4 \right)}$$
(21)

$$Z_{ino3} = \frac{Z_{03}^{2}}{(R/2)} = \frac{Z_{01}^{2}}{(R/2)}$$
(22)

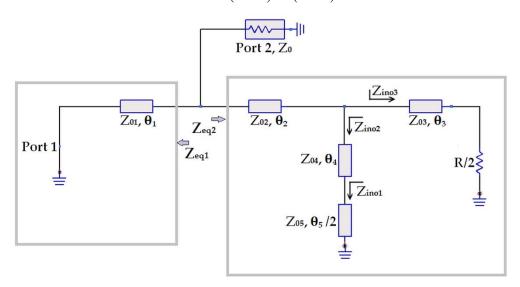


Fig. 7. Equivalent circuit of the proposed ring divider for even-mode.

The input impedance Z_{eq2} can be derived by using the quarter-wave transformer having characteristic impedance $Z_{02} = Z_{01}$, resulting in:

$$Z_{eq2} = Z_{01}^{2} (Y_{ino3} + Y_{ino2})$$
(23)

$$Z_{eq2} = \frac{R}{2} - \frac{jZ_{01}^{2} \left(Z_{04} - Z_{05} tan(\theta_{5} / 2) tan\theta_{4} \right)}{Z_{04} \left(Z_{04} tan\theta_{4} + Z_{05} tan(\theta_{5} / 2) \right)}$$
(24)

$$Y_{ino} = \frac{1}{Z_{eal}} + \frac{1}{Z_{ea2}} \tag{25}$$

$$Y_{ino} = \frac{1}{jZ_{01}tan\theta_{1}} + \frac{1}{\frac{R}{2} - \frac{jZ_{01}^{2}(Z_{04} - Z_{05}tan(\theta_{5}/2) tan\theta_{4})}{Z_{04}(Z_{04} tan\theta_{4} + Z_{05}tan(\theta_{5}/2))}} = \frac{1}{Z_{0}}$$
(26)

Since $\theta_1 = \pi/2$ and $Z_0 = R/2$; then after simplification, the matching condition in equation (26) becomes:

$$Z_{04} - Z_{05} tan(\theta_5 / 2) tan\theta_4 = 0$$
 (27)

Which is the first resonance condition given by (1) for the odd-mode resonance of a typical steppedimpedance resonator. Since the two conditions for even and odd mode resonance are satisfied, this proves that the added element is an SIR.

The SIR is designed with fixed fundamental frequency, but different first spurious mode (f_{s1}) by choosing different combinations of K and α from Fig. 5 and thereby the dimensions of the SIR can be determined. The impedance ratio K and the stepped percentage α are then tuned using electromagnetic (EM) simulation in order to consider step discontinuities [16].

It has been demonstrated that by changing the width ratio w_5/w_4 of the low-impedance (Z_{05}) line to the high-impedance (Z_{04}) line, which result in the modification of K, the position of the transmission zeros can be adjusted. Furthermore, it is evident that by increasing the width ratio w_5/w_4 , resonance frequency is varied [17].

A parametric study is conducted to evaluate the effect of SIR's characteristic impedance ratio on the bandwidth of the proposed power divider. Fig. 8 shows the effect of variation of K on the transmission S-parameter magnitude of the proposed power divider.

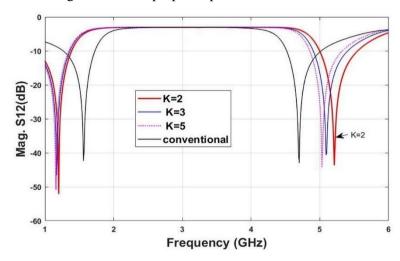


Fig. 8. Transmission S-parameter of proposed power divider with the variation of K.

It can be seen from Fig. 8, that when K increases, there is almost no effect on the lower transmission zero; however, the second transmission zero is shifted to a lower frequency. The

simulation results are also compared to the case of the conventional ring power divider (without SIR). It is noticed that for K = 2, we get the wider bandwidth with two transmission zeros situated at 1.2 GHz and 5.21 GHz with -52 dB and -44 dB attenuation values respectively.

Following the above guidelines, the optimized parameters of K=2 and α = 0.95 can be used in order to get a wide bandwidth from 1.7 GHz to 4.6 GHz of the proposed divider. As a result, the stepped impedance resonator can be designed to have the characteristic impedances Z_{04} =40 Ω and Z_{05} =20 Ω , and the electrical lengths θ_4 and θ_5 are set to 84.5° and 7.8° respectively. This can be used in order to calculate the dimensions of the Stepped Impedance Resonator (SIR) cell. The microstrip widths and lengths corresponding to characteristic impedances Z_0 , Z_{01} , Z_{04} and Z_{05} are shown in Table 1. The radius of the ring is 15 mm.

TABLE I. DIMENSIONS OF THE PROPOSED RING POWER DIVIDER

Characteristic Impedance Z_0 Z_{01} Z_{04} Z_{04}

Characteristic Impedance	Z_0	Z_{01}	Z_{04}	Z_{05}
Width (mm)	0.76	0.44	0.89	2.2
Length (mm)	18.8	23	30	1.3

Fig. 9 and Fig. 10 show the EM simulation results of the conventional and proposed ring power divider respectively obtained by using the Advanced Design System (ADS) software. As can be observed from these figures, the conventional ring structure [10] has a fractional bandwidth of 63 % ranging from 2.14 GHz to 4.11 GHz (S_{11} <-10 dB), while simulations of the proposed ring structure show that the fractional bandwidth has increased up to 90.2 % producing therefore a remarkable bandwidth enhancement of 27.2 % as mentioned in section 1. By comparing the results of the two ring power dividers, we can notice that the proposed ring power divider has an insertion loss which is between -3.04 dB and -3.58 dB over the whole band (1.74- 4.6 GHz) with quasi-null amplitude imbalance (S_{21} = S_{31}) while the conventional power divider has an insertion loss between -3.06 dB and -3.61 dB over a narrower band (2.14- 4.11 GHz). In addition, it is obvious that the proposed divider has better return loss and better isolation between the output ports which are lower than -10 dB in the whole band (1.74- 4.6 GHz), providing thus a significant wide bandwidth contribution compared to the previous reported ring divider which operates from 2.14 GHz to 4.11 GHz as can be clearly seen from Fig. 9 and Fig. 10.

Compared with other wideband power dividers present in the literature such as in [8]-[9], it is obvious that apart from its simpler structure, the proposed ring power divider has better performance over a wider operational bandwidth. It is to be noted that the power dividers developed in [8]-[9] have a fractional bandwidth of 68.6 % and 62 % respectively.

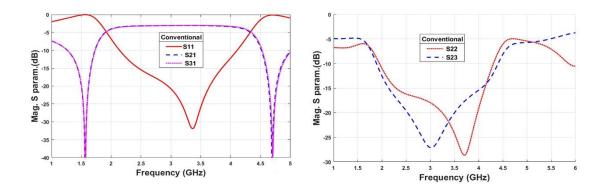


Fig. 9. Simulated S-parameters of the conventional power divider: (a) S₁₁, S₂₁ & S₃₁ and (b) S₂₂ & S₂₃.

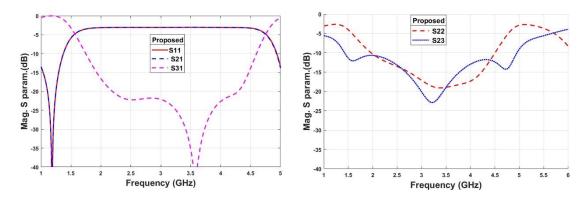


Fig. 10. Simulated S-parameters of the proposed power divider: (a) S₁₁, S₂₁ & S₃₁ and (b) S₂₂ & S₂₃.

III. FABRICATION AND MEASUREMENT RESULTS

For verification of the theoretical results, the proposed power divider has been fabricated on a Rogers RT/Duroid 6002 substrate whose dielectric constant is 2.93, loss tangent of 0.0013 and its thickness 0.254 mm. It operates at the center frequency of 3.17 GHz and has a large bandwidth (1.7-4.64 GHz) as expected. The fabricated ring power divider is shown in Fig. 11 and it occupies a small surface area of $5.1 \text{ cm} \times 5.5 \text{ cm}$.

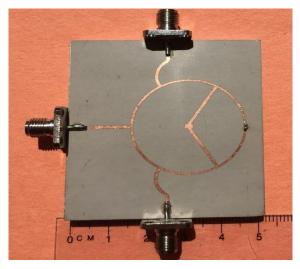


Fig. 11. Photograph of the fabricated ring power divider.

The S-parameter measurements were accomplished using the Agilent E8362B vector network analyzer over the frequency range from 1 to 6 GHz. The EM simulations and measured S-parameter results of the proposed power divider are shown in Fig. 12 and Fig. 13. The measurement results show that the proposed power divider has an insertion loss of 0.74 ranging from - 3.36 dB to - 4.1 dB between 1.74 GHz and 4.64 GHz. The measured return loss is less than -10 dB from 1.6 GHz to 4.71 GHz. The output return loss is lower than -10 dB from 1.7 GHz to 4.64 GHz. The isolation between the outputs is better than -10 dB between 1.42 GHz to 5.21 GHz. It can be concluded by comparing the measurement and EM simulation results that there is good agreement over the whole band of interest.

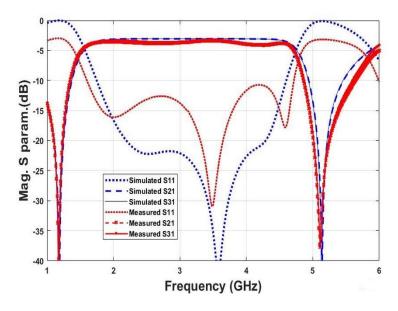


Fig. 12. Simulated and measured input return loss and insertion loss of the proposed divider.

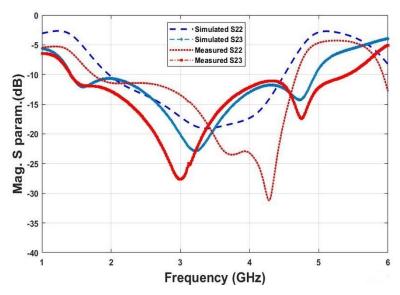


Fig. 13. Simulated and measured output return loss and isolation of the proposed divider.

The measured amplitude and phase imbalances between outputs of the proposed divider are shown in Fig. 14. These results show that the proposed power divider has a maximum amplitude imbalance Brazilian Microwave and Optoelectronics Society-SBMO received 23 June 2019; for review 27 June 2019; accepted 18 Nov 2019 Brazilian Society of Electromagnetism-SBMag © 2020 SBMO/SBMag ISSN 2179-1074

of 0.21 dB in the whole band from 1.7 GHz to 4.64 GHz which implies that the power is divided evenly between the 2 outputs. In addition, the two outputs are in-phase in the whole band with a tolerance of less than 2.5 degrees over the whole bandwidth of interest which proves the good phase performance of the fabricated power divider.

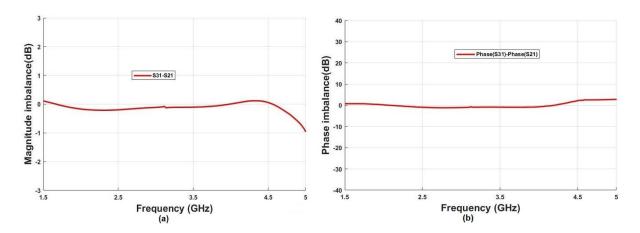


Fig. 14. Measured outputs imbalance of the proposed power divider: (a) Magnitude and (b) Phase.

IV. CONCLUSION

In this work, we have designed a modified ring power divider to cover the frequency bandwidth of 1.7 GHz to 4.6 GHz by adding an SIR to the old structure to improve its operational bandwidth. A detailed even-odd mode analysis of the proposed ring power divider has been performed. To validate the theoretical analysis and simulations, a prototype is fabricated on a single layer substrate. The experimental results show that the proposed circuit is broadband with a high factor amplitude balance over the considered bandwidth. The proposed ring power divider has the advantages of compact size and ease of fabrication which makes it very suitable for many wideband microwave applications.

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